

Technical Data Sheet

Opto Interrupter

EAITRDA7

Features

- Fast response time
- High analytic
- High sensitivity
- Cut-off visible wavelength $\lambda_P=940\text{nm}$
- Pb Free
- This product itself will remain within RoHS compliant version.



Description

The **EAITRDA7** consist of an infrared emitting diode and an NPN silicon phototransistor, encased side-by-side on converging optical axis in a black Thermoplastic Housing. The phototransistor receives radiation from the IR LED only .This is the normal Situation. But when an object is in between , phototransistor could not receives the radiation.

For additional component information , please refer to IR204 and PT204-6B

Applications

- Mouse Copier
- Switch Scanner
- Floppy disk driver
- Non-contact Switching
- For Direct Board

Device Selection Guide

Device No.	Chip Material	LENS COLOR
IR	GaAlAs	Blue
PT	Silicon	Black

Absolute Maximum Ratings (Ta=25°C)

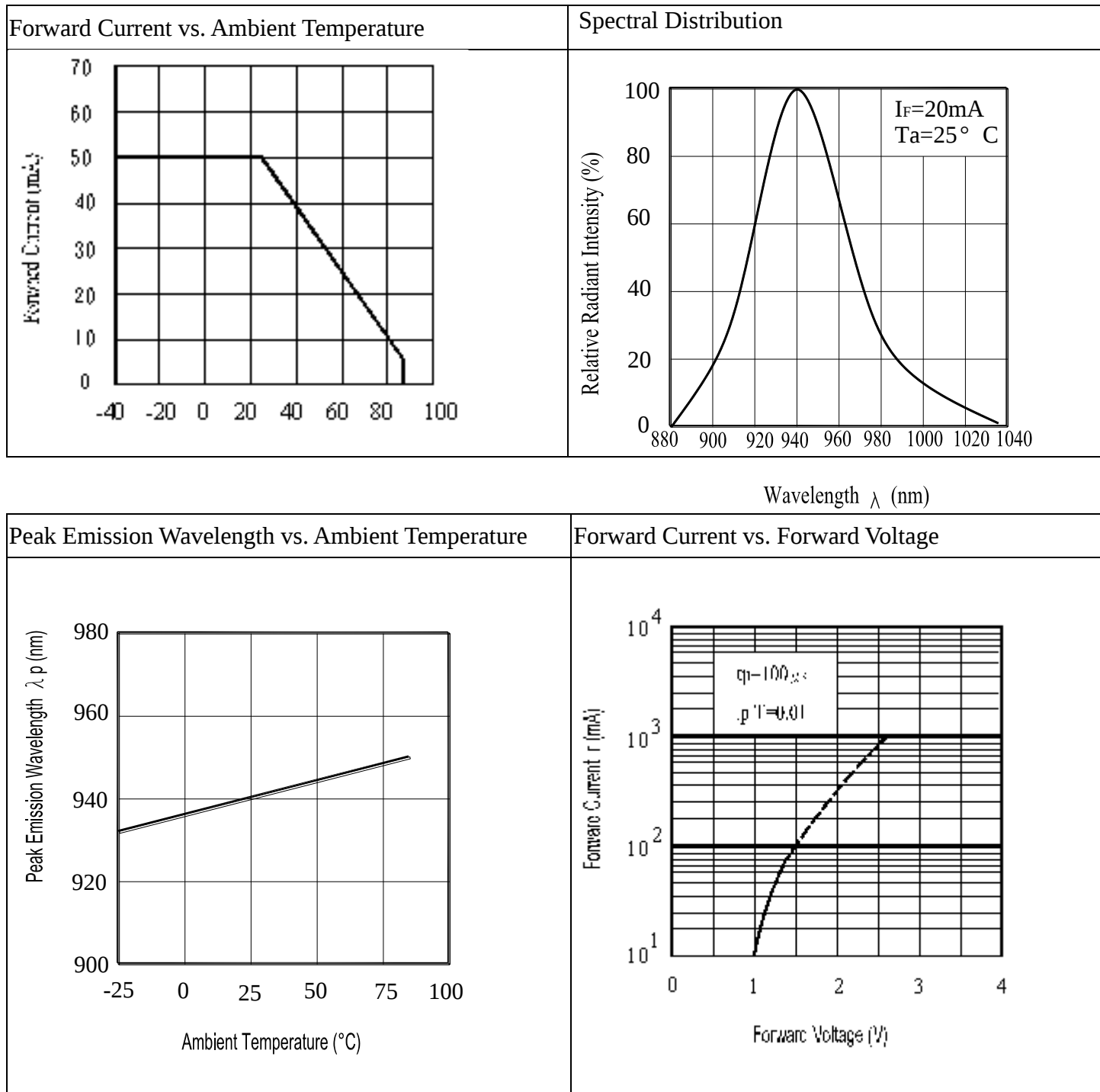
Parameter		Symbol	Ratings	Unit
Input	Power Dissipation at(or below) 25°C Free Air Temperature	Pd	75	mW
	Reverse Voltage	V _R	5	V
	Forward Current	I _F	50	mA
	Peak Forward Current (*1) Pulse width ≤100μs, Duty cycle=1%	I _{FP}	1	A
Output	Collector Power Dissipation	P _C	75	mW
	Collector Current	I _C	20	mA
	Collector-Emitter Voltage	B V _{CEO}	30	V
	Emitter-Collector Voltage	B V _{ECO}	5	V
Operating Temperature		Topr	-25~+85	°C
Storage Temperature		Tstg	-40~+100	°C
Lead Soldering Temperature (*2) (1/16 inch form body for 5 seconds)		Tsol	260	°C

Notes: (* 1) $t_w=100 \mu\text{sec.}$, $T=10 \text{ msec.}$ (* 2) $t=5 \text{ Sec}$

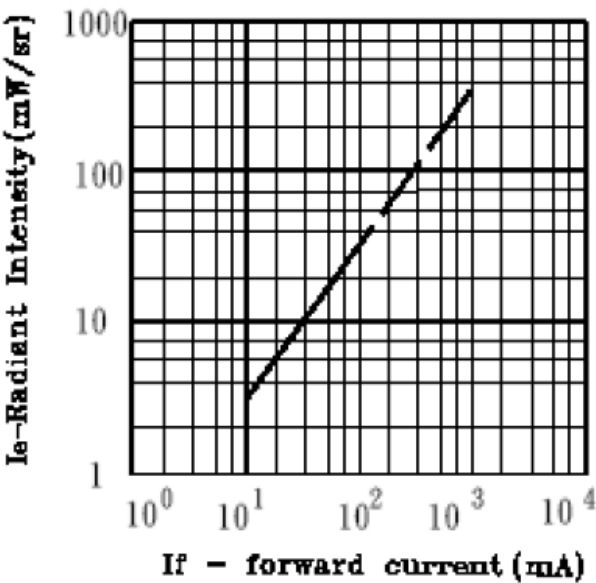
Electro-Optical Characteristics (Ta=25°C)

Parameter		Symbol	Min.	Typ.	Max.	Unit	Condition
Input	Forward Voltage	V_{F1}	-	1.2	1.5	V	$I_F=20\text{mA}$
		V_{F2}	-	1.4	1.85		$I_F=100\text{mA}, t_p=100\mu\text{s}, t_p/T=0.01$
		V_{F3}	-	2.6	4.0		$I_F=1\text{A}, t_p=100\mu\text{s}, t_p/T=0.01$
	Reverse Current	I_R	-	-	10	μA	$V_R=5\text{V}$
	Peak Wavelength	λ_p	-	940	-	nm	$I_F=20\text{mA}$
Output	Dark Current	I_{CEO}	-	-	100	nA	$V_{CE}=20\text{V}, E_e=0\text{mW}/\text{cm}^2$
	C-E Saturation Voltage	$V_{CE(sat)}$	-	-	0.4	V	$I_C=2\text{mA}, E_e=1\text{mW}/\text{cm}$
Collector Current		$I_{C(ON)}$	0.5	-	20	mA	$V_{CE}=3\text{V}, I_F=40\text{mA}$
Response Time	Rise Time	t_R	-	15	-	μs	$V_{CE}=5\text{V}, I_C=1\text{mA}, R_L=1\text{K}\Omega$
	Fall Time	t_F	-	15	-	μs	

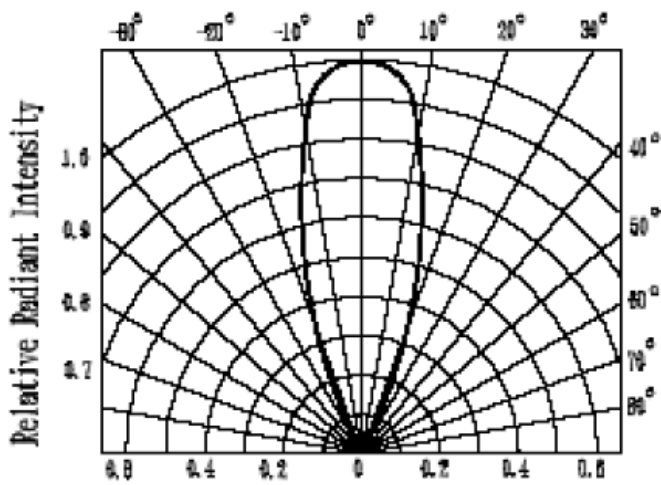
Typical Electrical/Optical/Characteristics Curves for IR



Radiant Intensity vs. Forward Current

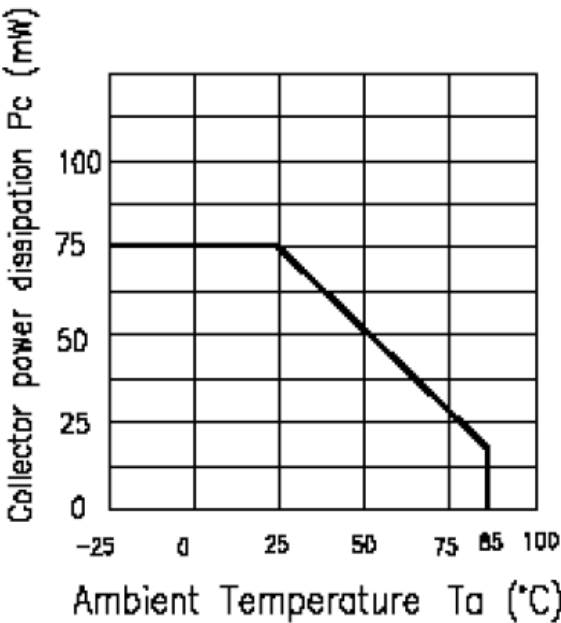


Relative Radiant Intensity vs. Angular Displacement

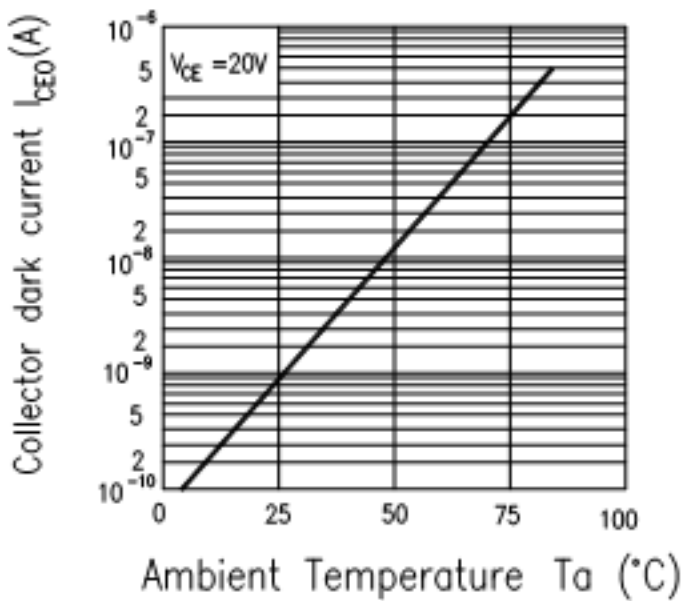


Typical Electro/Optical/Characteristics Curves for PT

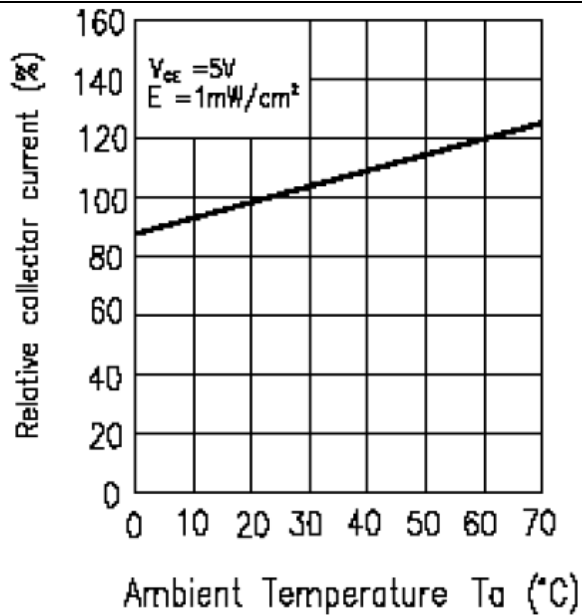
Collector Power Dissipation vs. Ambient Temperature



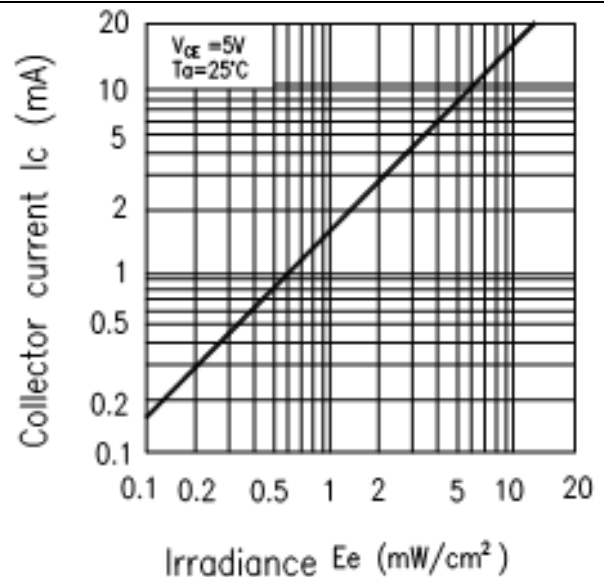
Relative Collector Current vs. Ambient Temperature



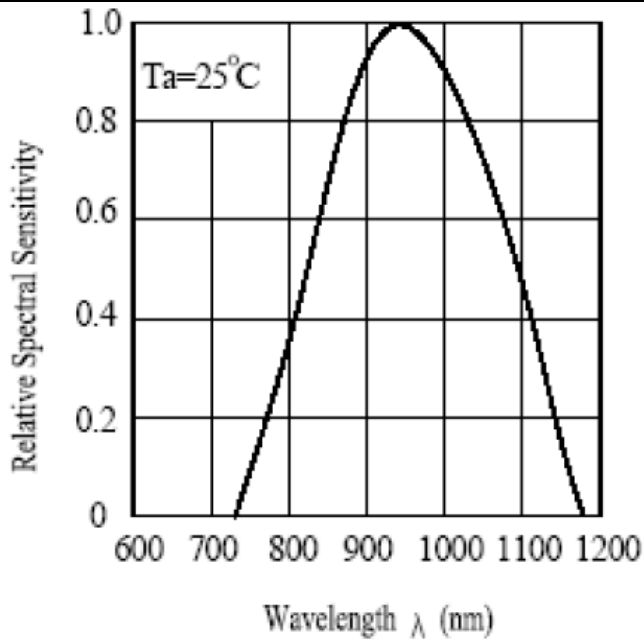
Relative collector current vs. Ambient Temperature



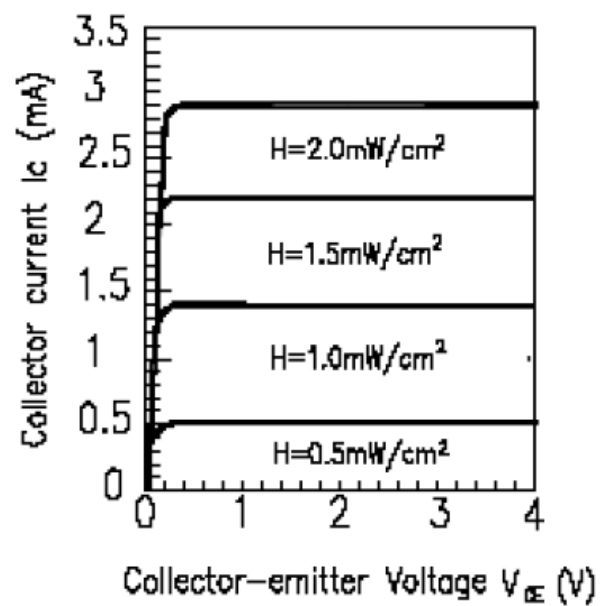
Collector Current vs. Irradiance



Relative Sensitivity vs. Wavelength



Collector current vs. Collector-Emitter Voltage



Reliability Test Item And Condition

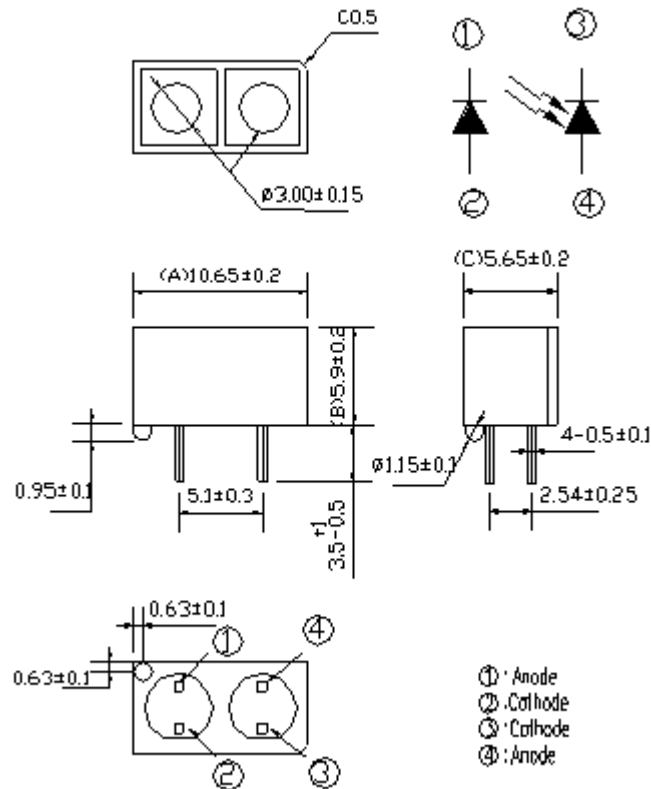
The reliability of products shall be satisfied with items listed below.

Confidence level : 90%

LTPD : 10%

NO.	Item	Test Condition	Test Hours/ Cycle	Sample Size	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP : 260°C ± 5 °C	10 sec	22 PCs	$I_{c(on)} \leq L \times 0.8$ L :Lower specification limit	0/1
2	Temperature Cycle	H : +100°C 15 mins  5 min L : -40°C 15 min 	300 cycle	22 PCs		0/1
3	Thermal Shock	H : +100°C 5 min  10 sec L : -10°C 5 min 	300 cycle	22 PCs		0/1
4	High Temperature Storage	TEMP. : +100°C	1000 hrs	22 PCs		0/1
5	Low Temperature Storage	TEMP. : -40°C	1000 hrs	22 PCs		0/1
6	DC Operating Life	V _{CE} =5V I _F =20mA	1000 hrs	22 PCs		0/1
7	High Temperature / High Humidity	85°C / 85% R.H.	1000 hrs	22 PCs		0/1

Package Dimension



Notes:

1. All dimensions are in millimeters
2. Tolerances unless dimensions ± 0.2 mm
3. Lead spacing is measured where the lead emerge from the package
4. Above specification may be changed without notice. EVERLIGHT Americas will reserve authority on material change for above specification
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6. When using this product , please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERIGHT Americas assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.

Packing Quantity Specification

1. 200 pcs/1bag , 6 bags/1box
2. 10 boxes/1carton

Label Form Specification

Pb **EVERLIGHT AMERICA**

CPN: XXXXXXXXXXXX
P/N: XXXXXXXXXXXX
XXXXXXXXXXXXXXXXXXXX
QTY: XXXX
LOT NO: XXXXXXXXXXXXXXXXXXXX
REFERENCE: XXXXXXXXXXXX
CAT: XXX
HUE: XXX
REF: XXX
MADE IN TAIWAN

RoHS

- CPN: Customer's Product Number
- P/N: Product Number
- QTY: Packing Quantity
- CAT: Luminous Intensity Rank
- HUE: Dom. Wavelength Rank
- REF: Forward Voltage Rank
- LOT No: Lot Number
- X: Month
- Reference: Identify Label Number

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